Product data sheet

1. General description

Ultrafast power diode in a SMA package.

2. Features and benefits

- Fast switching
- SMA package
- · High voltage capability
- Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- · Soft recovery characteristic

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- Switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit		
Absolute	Absolute maximum rating					
V_{RRM}	repetitive peak reverse voltage		600	V		
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le$ 140 °C; Fig. 1; Fig. 2; Fig. 3	1	A		
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{lead} ≤ 140 °C; square-wave pulse	2	A		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	39	A		
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	43	Α		

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 A
2	Α	anode	1 2	K

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MURS160	SMA	MURS160J	Reel	7500	SMAE	03-Mar-2020

7. Marking

Table 4. Marking codes

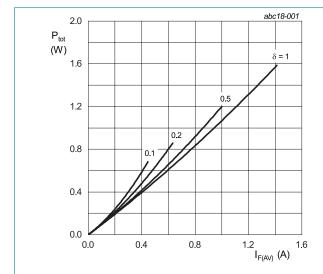
Table 4. Warking codes	
Type number	Marking codes
MURS160	S160

8. Limiting values

Table 5. Limiting values

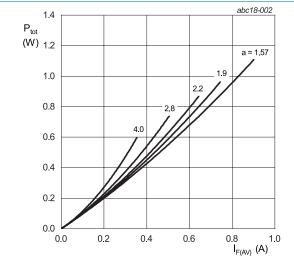
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le$ 140 °C; Fig. 1; Fig. 2; Fig. 3	1	Α
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{lead} \le$ 140 °C; square-wave pulse	2	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	39	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	43	Α
T _{stg}	storage temperature		-65 to 175	°C
T _j	junction temperature		175	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 0.934 \text{ V}; \text{ R}_s = 0.1331 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

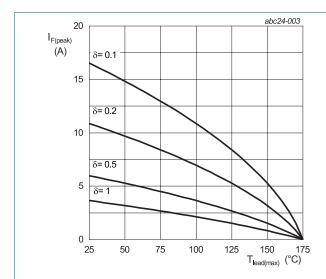


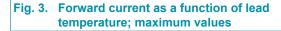
a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.934 V; R_s = 0.1331 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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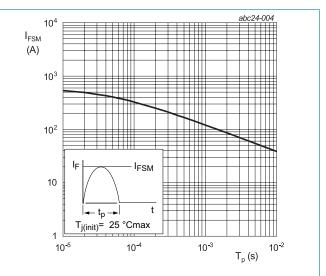


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 5</u>	-	-	29	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	-	216	K/W

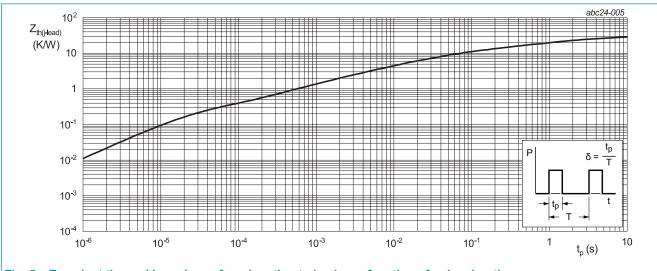
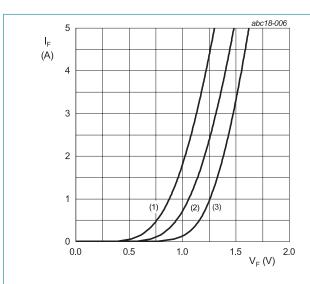


Fig. 5. Transient thermal impedance from junction to lead as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cl	naracteristics					
V_{F}	forward voltage	I _F = 1 A; T _j = 25 °C	-	-	1.25	V
		I _F = 1 A; T _j = 150 °C	-	-	1.05	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	5	μA
		V _R = 600 V; T _j = 150 °C	-	-	150	μA
Dynamic	characteristics					
Q _r	reverse charge	$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	45	-	nC
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$	-	81	-	nC
t _{rr} reverse	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	-	75	ns
		$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step recovery}$	-	-	56	ns
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	31	-	ns
		$I_F = 1 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/us}$; $T_j = 125 \text{ °C}$; Fig. 7	-	46	-	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/us}$; $T_J = 25 \text{ °C}$; Fig. 7	-	2.9	-	А
		$I_F = 1 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/us}$; $T_j = 125 \text{ °C}$; Fig. 7	-	3.5	-	А
E _{as}	non-repetitive avalanche energy	$I_R = 0.9 \text{ A}; L = 15 \text{ mH}; T_{j(init)} = 25 ^{\circ}\text{C}$	6	-	-	mJ



 V_o = 0.934 V; R_s = 0.1331 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values



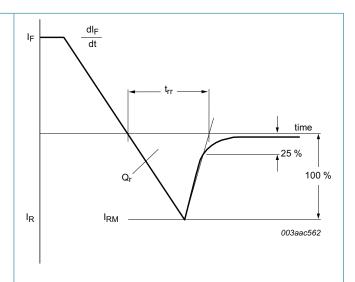
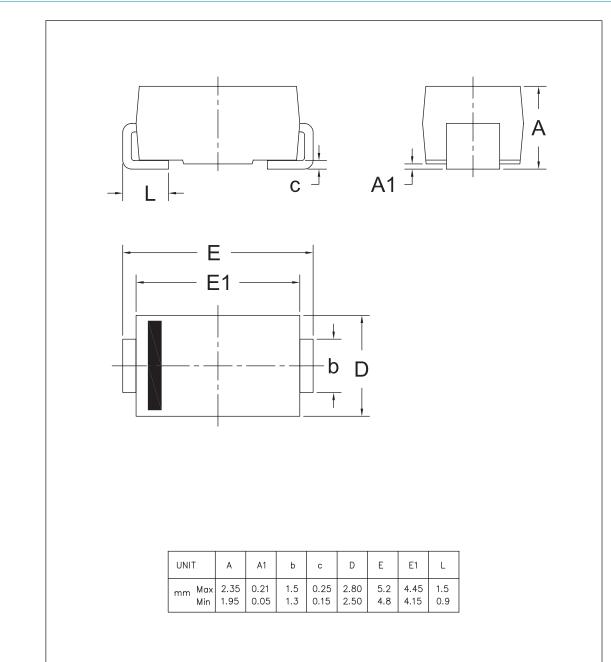


Fig. 7. Reverse recovery definitions; ramp recovery

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11. Package outline



Remark: Dimensions D and E1 do not include mold flash.

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12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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